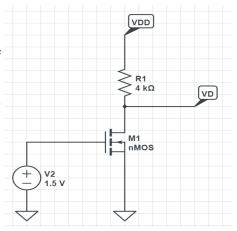
## BRAC University (Department of Computer Science and Engineering) CSE 460 (VLSI Design) | Fall 2023

## **Assignment 1**

- 1. Design the simplest sum-of-products circuit that implements the function  $f(x1, x2, x3) = \sum m(3, 4, 6, 7)$ . Using K-maps
- 2. Design the simplest sum-of-products circuit that implements the function  $f(x1, x2, x3) = \sum m(1,3,4,6,7)$ . Using K-maps
- 3. Design the simplest circuit that has three inputs, x1, x2, and x3, which produces an output value of 1 whenever exactly one or two of the input variables have the value 1; otherwise, the output has to be 0. [ hint: you have to make the truth table first, then use K-map to simplify ]
- 4. Repeat Problem 2 for the function  $f(x_1, x_2, x_3) = m(1, 4, 7) + D(2, 5)$ .
- 5. find the minimum sum-of-products expression for the function f = x1x3 + x1(x2)' + (x1)'x2x3 + (x1)'(x2)'(x3)'.
- 6. Consider the following circuit where an n-channel MOSFET in 180nm process is shown. The following parameters are given for the M1, [7 Marks]

## $\mu$ nCox = 100 $\mu$ A/V2, Vt = 0.5 V, VDD=4V, VD=1V

- a. Calculate the current through the MOSFET and find the Necessary width W to attain that current.
- b. Again, assume that  $W=1.8 \mu m$ . Now find the value of R1 that results in the given drain voltage VD.



7. Explain the behavior/operating region of a MOS with following I-V characteristics at points A and B with necessary equations

